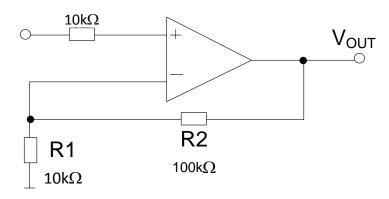


Typical Applications Circuit

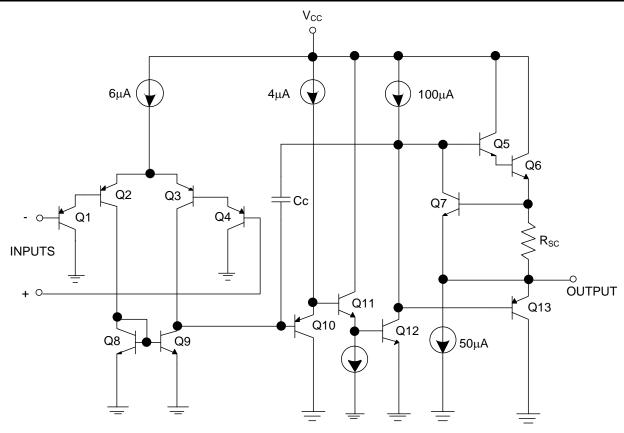


Pin Descriptions

Pin Number	Pin Name	Function	
LM2902Q, LM2902AQ			
1	1OUT	Channel 1 Output	
2	1IN-	Channel 1 Inverting Input	
3	1IN+	Channel 1 Non-Inverting Input	
4	VCC	Chip Supply Voltage	
5	2IN+	Channel 2 Non-Inverting Input	
6	2IN-	Channel 2 Inverting Input	
7	2OUT	Channel 2 Output	
8	3OUT	Channel 3 Output	
9	3IN-	Channel 3 Inverting Input	
10	3IN+	Channel 3 Non-inverting Input	
11	GND	Ground	
12	4IN+	Channel 4 Non-Inverting Input	
13	4IN-	Channel 4 Inverting Input	
14	4OUT	Channel 4 Output	
LM2904Q, LM2904AQ			
1	10UT	Channel 1 Output	
2	1IN-	Channel 1 Inverting Input	
3	1IN+	Channel 1 Non-inverting Input	
4	GND	Ground	
5	2IN+	Channel 2 Non-Inverting Input	
6	2IN-	Channel 2 Inverting Input	
7	2OUT	Channel 2 Output	
8	VCC	Chip Supply Voltage	



Functional Block Diagram



Functional Block Diagram of LM2902Q/ LM2902AQ/ LM2904Q/ LM2904AQ (Each Amplifier)

Absolute Maximum Ratings (Note 5) (@T_A = +25°C, unless otherwise specified.)

Symbol	Paramet	Parameter		
Vcc	Supply Voltage		±18 or 36	V
V _{ID}	Differential Input Voltage		36	V
VIN	Input Voltage		-0.3 to +36	V
		LM2904_QS	150	
	Package Thermal Impedance (Note 6)	LM2904_QTH	175	
θ_{JA}		LM2904_QM8	200	°C/W
		LM2902_QS14	89]
		LM2902_QT14	100]
_	Output Short-Circuit to GND (One Amplifier) (Note 7)	V _{CC} ≤ 15V and T _A = +25°C	Continuous	_
TA	Operating Temperature Range		-40 to +125	°C
TJ	Operating Junction Temperature		+150	°C
T _{STG}	Storage Temperature Range		-65 to +150	°C

Notes: 5. Stresses beyond those listed under *Absolute Maximum Ratings* can cause permanent damage to the device. These are stress ratings only, functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to

absolute-maximum-rated conditions for extended periods can affect device reliability.

6. Maximum power dissipation is a function of $T_{J(MAX)}$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_{J(MAX)} - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of +150°C can affect reliability.

^{7.} Short circuits from outputs to V_{CC} or ground can cause excessive heating and eventual destruction.



ESD Ratings

Parameter	Rating	Unit	
	LM2902_QS14	500	
	LM2902_QT14	500	
Human Body Mode ESD Protection (Note 8)	LM2904_QS	500	
	LM2904_QTH	500	
	LM2904_QM8	<500	V
	LM2902_QS14		v
	LM2902_QT14		
Charge Device Mode ESD Protection	LM2904_QS	1,000	
	LM2904_QTH		
	LM2904_QM8		

Note: 8. Human body model, $1.5k\Omega$ in series with 100pF.

Recommended Operating Conditions (Over Operating Free-Air Temperature Range, unless otherwise noted.)

Parameter	Min	Max	Unit	
Cupply Voltage	Single Supply	2	36	V
Supply Voltage	Dual Supply	±1	±18	V
Ambient Temperature Range	-40	+125	°C	
Junction Temperature Range		-40	+125	



Electrical Characteristics (Notes 12 and 13) (@ V_{CC} = +5.0V, T_A = +25°C, unless otherwise specified.) (LM2902Q, LM2902AQ)

Symbol	Paramet	er	Conditions		T _A	Min	Тур	Max	Unit
			V _{IC} = V _{CMR} Minimum,	Non-A	T _A = +25°C	_	2	7	
\/.a	Input Offset Voltage	, , , , , , , , , , , , , , , , , , ,	$V_0 = 1.4V$,	Device	Full Range	_	_	10	mV
VIO	V _{IO} Input Offset Voltage		V _{CC} = 5V to Maximum	A-Suffix	$T_A = +25^{\circ}C$	_	1	2	IIIV
			$R_S = 0\Omega$	Device	Full Range	_	_	4	
ΔV _{IO} /ΔΤ	Input Offset Voltage ⁻ Drift	Temperature	$R_S = 0\Omega$		Full Range	_	7		μV/°C
I _B	Input Bias Current		I _{IN+} or I _{IN} - with OUT in Line	ear Range,	$T_A = +25$ °C	_	-20	-200	nA
iВ	input bias current		V _{CMR} = 0V (Note 9)		Full Range	_	_	-500	ПА
I _{IO}	Input Offset Current		$I_{IN+} - I_{IN-}, V_{CM} = 0V$		$T_A = +25$ °C	_	2	50	nA
110	input Onset Current		11N+ - 11N-, VCM = 0V		Full Range	_	_	150	ПА
ΔΙ _{ΙΟ} /ΔΤ	Input Offset Current 7 Drift	Temperature	_		Full Range	_	10	_	pA/°C
Vaus	V _{CMR} Input Common-Mode Voltage Range		V _{CC} = 30V (Note 10)		T _A = +25°C	0 to V _{CC} -1.5		1	V
VCMR			, ,		Full Range	0 to V _{CC} -2.0	_	1	
	Supply Current		$V_O = 0.5 V_{CC}$, No Load V_C	c = 30V	Full Range	_	1.0	3.0	mA
I _{CC}	(Four Amplifiers)		$V_O = 0.5 V_{CC}$, No Load $V_{CC} = 5V$		Full Range	_	0.7	1.2	IIIA
۸.,	Voltage Gain	$V_{CC} = 15V, V_{OUT} = 1V \text{ to } 11V,$ $T_A = +29$		T _A = +25°C	25	100	1	V/mV	
A _V	Voltage Gaill		$R_L \ge 2k\Omega$		Full Range	15	_		V/IIIV
CMRR	Common Mode Rejec	ction Ratio	DC, $V_{CMR} = 0V$ to V_{CC} -1.5	V	$T_A = +25^{\circ}C$	60	70	_	dB
PSRR	Power Supply Reject	ion Ratio	$V_{CC} = 5V$ to $30V$		$T_A = +25$ °C	70	100	-	dB
_	Amplifier to Amplifier	Coupling	f = 1kHz to 20kHz (Input Referred) (Note 11)		T _A = +25°C	_	-120	_	dB
		Sink	$V_{IN-} = 1V$, $V_{IN+} = 0V$, $V_{CC} = V_O = 200 \text{mV}$	15V,	T _A = +25°C	12	50		μA
I _{SINK}	Output Current	SITIK	$V_{IN-} = 1V, V_{IN+} = 0V, V_{CC} =$	15V,	T _A = +25°C	10	20	_	
	Output Current		V _O = 15V		Full Range	5	_	-	
looupor		Source	$V_{IN+} = 1V$, $V_{IN-} = 0V$, $V_{CC} = 15V$,		$T_A = +25$ °C	-20	-40	-60	- mA
ISOURCE		Source	V _O = 0V		Full Range	-10	_		
I _{SC}	Short-Circuit to Groun	nd	$V_{CC} = 5V$, $GND = -5V$, $V_O = 0V$		$T_A = +25^{\circ}C$	_	±40	±60	mA
			$R_L = 10k\Omega$		$T_A = +25^{\circ}C$	_	V _{CC} -1.5	_]
V _{OH}	High-Level Output Vo	oltage Swing	$R_L = 2k\Omega$	Σ	Full Panca	26		1	V
			$V_{CC} = 30V$ $R_L \ge 10k$	kΩ	Full Range	27	28		
V_{OL}	Low-Level Output Vo	Itage Swing	$R_L \leqq 10k\Omega$		Full Range	_	5	20	mV

AC Electrical Characteristics (Notes 12 and 13) (@ $V_{CC} = \pm 15.0V$, $T_A = +25^{\circ}C$, unless otherwise specified.) (LM2902Q, LM2902AQ)

Symbol	Parameter	Conditions	Тур	Unit
SR	Slew Rate at Unity Gain	$R_L = 1M\Omega$, $C_L = 30pF$, $V_I = \pm 10V$	0.3	V/µs
B1	Unity Gain Bandwidth	$R_L = 1M\Omega$, $C_L = 20pF$	0.7	MHz
Vn	Equivalent Input Noise Voltage	$R_S = 100\Omega$, $V_I = 0V$, $f = 1kHz$	40	nV/√Hz

Notes:

- 9. The direction of the input current is out of the IC due to the PNP input stage. This current is essentially constant, independent of the state of the output so that no loading change exists on the input lines.
- 10. The input common-mode voltage of either input signal voltage should not be allowed to become negative by more than 0.3V (@ +25°C). The upper end of the common-mode voltage range is V_{CC} -1.5V (@ +25°C), but either or both inputs can go to +36V without damage, independent of the magnitude of V_{CC}.
- 11. Due to proximity of external components, ensure that coupling is not originating via stray capacitance between these external parts. This typically can be detected as this type of capacitance increases at higher frequencies.
- 12. Typical values are all at T_A = +25°C conditions and represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not guaranteed on shipped production material.
- 13. All limits are guaranteed by testing or statistical analysis. Limits over the full temperature (-40 ≤ T_A ≤ +125°C) are guaranteed by design, but not tested in production.



Electrical Characteristics (continued) (Notes 12 and 13) (@ V_{CC} = +5.0V, T_A = +25°C, unless otherwise specified.) (LM2904Q, LM2904AQ)

Symbol	Parai	meter	Condit	tions	T _A	Min	Тур	Max	Unit
			V _{IC} = V _{CMR} Min,	Non-A Device	T _A = +25°C	_	2	7	
Vio	Input Offset Volta	ae.	$V_{O} = 1.4V,$	Non-A Device	Full Range	_	_	10	mV
VIO	input Onset voltage		$V_{CC} = 5V \text{ to MAX}$	A-Suffix Device	$T_A = +25$ °C	_	1	2	111 V
			$R_S = 0\Omega$	/ Cullix Bevice	Full Range	_	_	4	
$\Delta V_{IO}/\Delta T$	Input Offset Volta Drift	ge Temperature	$R_S = 0\Omega$		Full Range	_	7	_	μV/°C
IB	Input Bias Curren	ıt	I _{IN+} or I _{IN-} with OUT ir	n Linear Range,	$T_A = +25^{\circ}C$	_	-20	-250	nA
ıB	input bias curren		V _{CMR} = 0V (Note 9)		Full Range	_	_	-500	ША
I _{IO}	Input Offset Curre	ent	$I_{IN+} - I_{IN-}, V_{CM} = 0V$		$T_A = +25$ °C	_	2	50	nA
10	'		TIN+ TIN-, VCIVI — OV		Full Range	_	_	150	100
$\Delta I_{IO}/\Delta T$	Input Offset Curre Drift	ent Temperature	_		Full Range	_	10	_	pA/°C
V	Input Common-M	ode Voltage			T _A = +25°C	0 to V _{CC} -1.5	_	_	.,
VCMR	V _{CMR} Range		V _{CC} = 30V (Note 10)		Full Range	0 to V _{CC} -2.0	_	_	- V
1	Supply Current		$V_O = 0.5 V_{CC}$, No Loa	d $V_{CC} = 30V$	Full Range	_	0.7	2.0	mA
Icc	(Two Amplifiers)		$V_O = 0.5 V_{CC}$, No Loa	d $V_{CC} = 5V$	Full Range	_	0.5	1.2	MA
Av	Voltage Gain		V _{CC} = 15V, V _{OUT} = 1V to 11V,		$T_A = +25^{\circ}C$	25	100	_	V/mV
AV	Voltage Gain		$R_L \ge 2k\Omega$,		Full Range	15	_	_	V/IIIV
CMRR	Common Mode R	ejection Ratio	DC, $V_{CMR} = 0V$ to V_{CC} -1.5V		T _A = +25°C	60	70	_	dB
PSRR	Power Supply Re	jection Ratio	V _{CC} = 5V to 30V		T _A = +25°C	70	100	_	dB
_	Amplifier to Ampl	ifier Coupling	f = 1kHz to 20kHz (No	ote 11)	T _A = +25°C	_	120	_	dB
			$V_{IN-} = 1V, V_{IN+} = 0V, V_{IN-} = 0V$	/ _{CC} = 15V,	T _A = +25°C	12	50	_	μΑ
Isink	Output Current	Sink	$V_{IN-} = 1V, V_{IN+} = 0V, V$	V _{IN} -= 1V, V _{IN} += 0V, V _{CC} = 15V,		10	20	_	
	Output Current		V _O = 15V		Full Range	5	_	_	
lanunan	Source		$V_{IN+} = 1V, V_{IN-} = 0V, V$	/ _{CC} = 15V,	$T_A = +25^{\circ}C$	-20	-40	-60	mA
ISOURCE		V _O = 0V		Full Range	-10	_	_		
Isc	Short-Circuit to Ground		$V_{CC} = 5V$, $GND = -5V$, V _O = 0V	T _A = +25°C	_	±40	±60	mA
			$R_L = 10k\Omega$		T _A = +25°C	V _{CC} -1.5	_	_	
VoH	High-Level Outpu	t Voltage Swing	$V_{CC} = 30V$	= 2kΩ	Full Range	26	_	_	V
			RL:	= 30V R _L ≥ 10kΩ		27	28	_	
V_{OL}	Low-Lever Outpu	t Voltage Swing	$R_L \le 10 k\Omega$		Full Range	_	5	20	mV

AC Electrical Characteristics (continued) (Notes 12 and 13) (@ $V_{CC} = \pm 15.0V$, $T_A = +25^{\circ}C$, unless otherwise specified.) (LM2904Q, LM2904AQ)

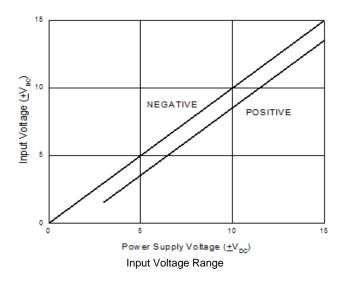
Symbol	Parameter	Conditions	Тур	Unit
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B1	Unity Gain Bandwidth	$R_L = 1M\Omega$, $C_L = 20pF$	0.7	MHz
Vn	Equivalent Input Noise Voltage	$R_S = 100\Omega$, $V_I = 0V$, $f = 1kHz$	40	nV/√Hz

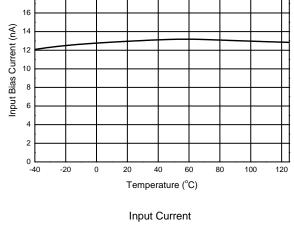
Notes:

- 9. The direction of the input current is out of the IC due to the PNP input stage. This current is essentially constant, independent of the state of the output so that no loading change exists on the input lines.
- 10. The input common-mode voltage of either input signal voltage should not be allowed to become negative by more than 0.3V (@ +25°C). The upper end of the common-mode voltage range is V_{CC} -1.5V (@ +25°C), but either or both inputs can go to +36V without damage, independent of the magnitude of V_{CC}.
- 11. Due to proximity of external components, ensure that coupling is not originating via stray capacitance between these external parts. This typically can be detected as this type of capacitance increases at higher frequencies.
- 12. Typical values are all at T_A = +25°C conditions and represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not guaranteed on shipped production material.
- 13. All limits are guaranteed by testing or statistical analysis. Limits over the full temperature (-40 ≤ T_A ≤ +125°C) are guaranteed by design, but not tested in production.

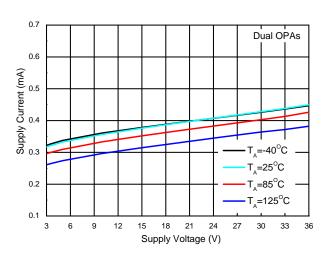


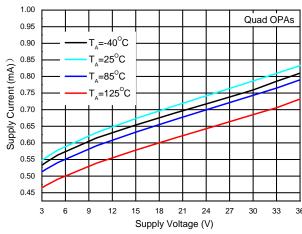
Performance Characteristics



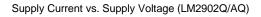


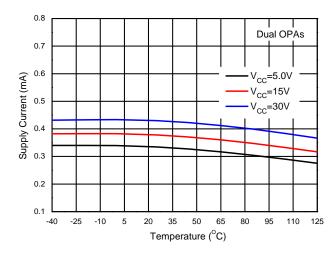
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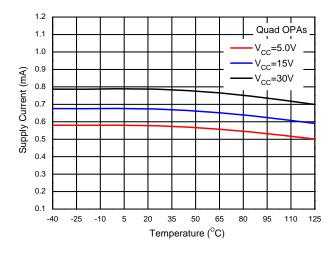




Supply Current vs. Supply Voltage (LM2904Q/4AQ)





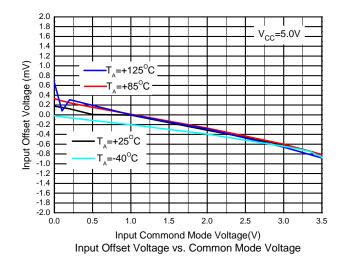


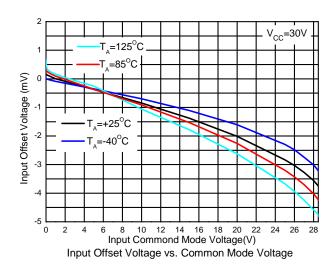
Supply Current vs. Temperature (LM2904Q/AQ)

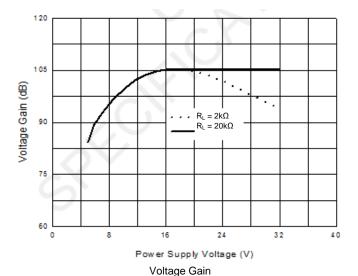
Supply Current vs. Temperature (LM2902Q/AQ)

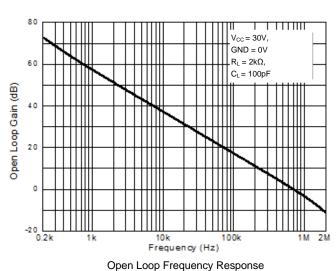


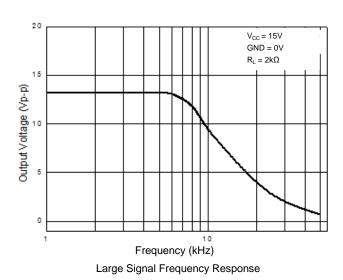
Performance Characteristics (continued)

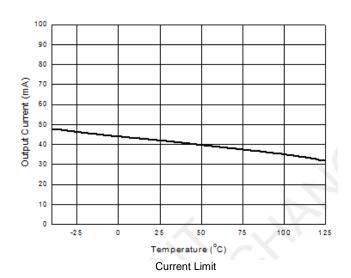






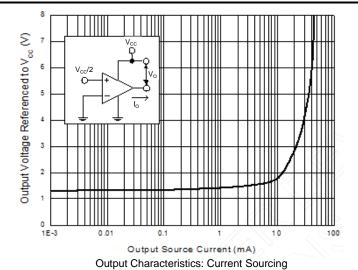


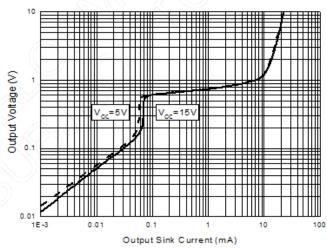




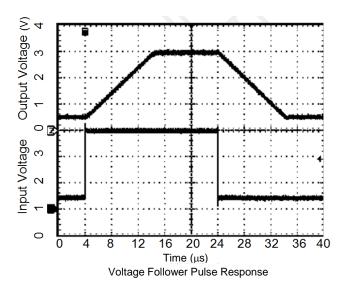


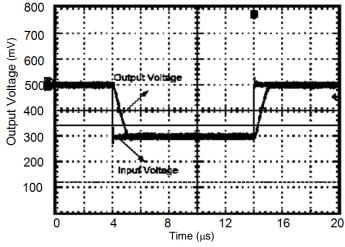
Performance Characteristics (continued)





Output Characteristics: Current Sinking





Voltage Follower Pulse Response (Small Signal)





Application Information

General Information

The LM2902Q/LM2902AQ/LM2904Q/LM2904AQ series op amps which operate with only a single power supply voltage, have true-differential inputs and remain in the linear mode with an input common-mode voltage of 0V. These amplifiers operate over a wide range of power supply voltage with little change in performance characteristics. At +25°C, amplifier operation is possible down to a minimum supply voltage of 2.3V.

Precautions should be taken to ensure that the power supply for the integrated circuit never becomes reversed in polarity, or that the unit is not inadvertently installed backwards in a test socket. If precaution is not taken, an unlimited current surge through the resulting forward diode within the IC may occur and could cause fusing of the internal conductors, destroying the unit.

Large differential input voltages can be easily accommodated and, as input differential voltage protection diodes are not needed, no large input currents result from large differential input voltages. The differential input voltage may be larger than V^+ without damaging the device. Protection should be provided to prevent the input voltages from becoming negative more than -0.3V (@ +25°C). An input clamp diode with a resistor to the IC input terminal can be used.

To reduce the power supply current drain, the amplifiers have a class A output stage for small signal levels which converts to class B in a large signal mode. This allows the amplifiers to achieve both source and sink large output currents. Therefore both NPN and PNP external current boost transistors can be used to extend the power capability of the basic amplifiers. The output voltage needs to raise approximately 1 diode drop above ground to bias the on-chip vertical PNP transistor for output current sinking applications.

For AC applications where the load is capacitive coupled to the output of the amplifier, a resistor should be used from the output of the amplifier to ground to increase the class A bias current, and prevent crossover distortion. Where the load is directly coupled, as in DC applications, there is no crossover distortion.

Capacitive loads which are applied directly to the output of the amplifier reduce the loop stability margin. Values of 50pF can be accommodated using the worst-case non-inverting unity gain connection. Large closed loop gains or resistive isolation should be used if larger load capacitance must be driven by the amplifier.

The bias network of the LM2902Q/LM2902AQ/LM2904QQ/LM2904AQ series establishes a quiescent current which is independent of the magnitude of the power supply voltage over the range of 3V to 30V.

Output short circuits either to ground or to the positive power supply should be of short time duration. Units can be destroyed, not as a result of the short circuit current causing metal fusing, but rather due to the large increase in IC chip dissipation which will cause eventual failure due to excessive function temperatures. Putting direct short-circuits on more than one amplifier at a time will increase the total IC power dissipation to destructive levels, if not properly protected with external dissipation limiting resistors in series with the output leads of the amplifiers. The larger value of output source current which is available at +25°C provides a larger output current capability at elevated temperatures (see *Typical Performance Characteristics*) than a standard IC op amp.

The circuits presented in Typical Applications section emphasize operation on a single power supply voltage. If complementary power supplies are available, all of the standard op amp circuits can be used. In general, introducing a pseudo-ground (a bias voltage reference of V_{CC}/2) will allow operation above and below this value in single power supply systems. Many application circuits are shown which take advantage of the wide input common-mode voltage range which includes ground. In most cases, input biasing is not required and input voltages which range to ground can easily be accommodated.



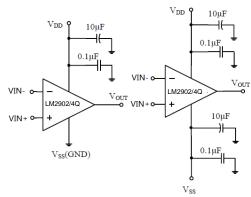
Application Information (continued)

Power Supply Bypassing and Layout

The LM2902Q/LM2902AQ/LM2904Q/LM2904AQ family operates from both single supply voltage ranging 3V to 36V, or dual supply voltage ±1.5V to ±18V.

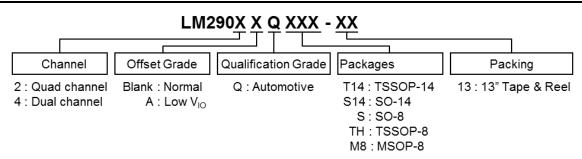
As with any operation amplifier, proper supply bypassing is critical for low noise performance and high power supply rejection. For single supply operation system, a minimum 0.1µF bypass capacitor should be recommended to place as close as possible between V_{CC} pin and GND. For dual supply operation, both the positive supply pin and negative supply pin should be bypassed to ground with a separate 0.1µF ceramic capacitor.

2.2µF tantalum capacitor can be added for better performance. Keep the length of leads and traces that connect capacitors between LM2902Q/LM2904Q/LM2904Q/LM2904AQ power supply pin and ground as short as possible.



Amplifier with Bypass Capacitors

Ordering Information



Part Number	Package	Packaging	13" Tape and Reel		Qualification
Fait Nullibei	Code	(Note 14)	Quantity	Part Number Suffix	(Note 15)
LM2902QT14-13	T14	TSSOP-14	2,500/Tape & Reel	-13	Automotive Compliant
LM2902AQT14-13	T14	TSSOP-14	2,500/Tape & Reel	-13	Automotive Compliant
LM2902QS14-13	S14	SO-14	2,500/Tape & Reel	-13	Automotive Compliant
LM2902AQS14-13	S14	SO-14	2,500/Tape & Reel	-13	Automotive Compliant
LM2904QS-13	S	SO-8	2,500/Tape & Reel	-13	Automotive Compliant
LM2904AQS-13	S	SO-8	2,500/Tape & Reel	-13	Automotive Compliant
LM2904QTH-13	TH	TSSOP-8	2,500/Tape & Reel	-13	Automotive Compliant
LM2904AQTH-13	TH	TSSOP-8	2,500/Tape & Reel	-13	Automotive Compliant
LM2904QM8-13	M8	MSOP-8	2,500/Tape & Reel	-13	Automotive Compliant
LM2904AQM8-13	M8	MSOP-8	2,500/Tape & Reel	-13	Automotive Compliant

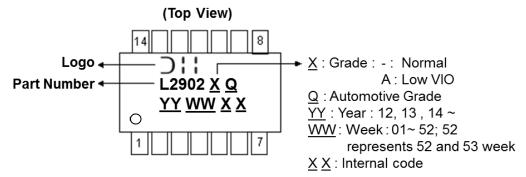
Notes: 14. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

^{15.} LM2902Q/LM2904AQ/LM2904AQ has been qualified to AEC-Q100 grade 1 and is classified as "Automotive Compliant" which supports PPAP documentation. See LM2902/2904 datasheet for commercial qualified versions.

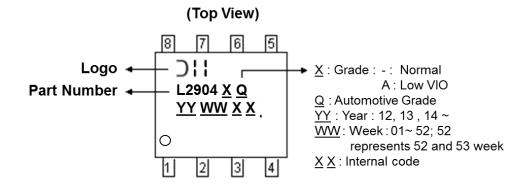


Marking Information

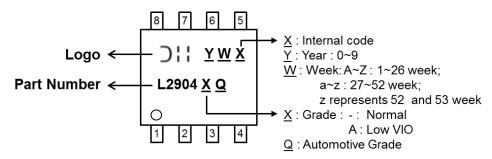
(1) TSSOP-14 and SO-14



(2) SO-8



(3) MSOP-8 and TSSOP-8

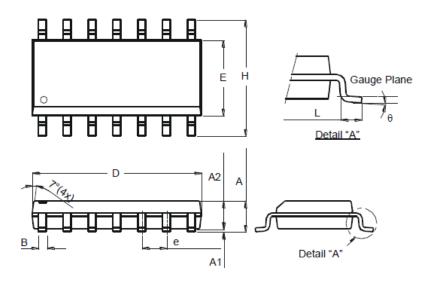




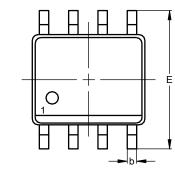
Package Outline Dimensions

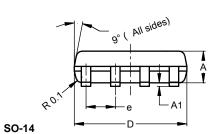
Please see http://www.diodes.com/package-outlines.html for the latest version.

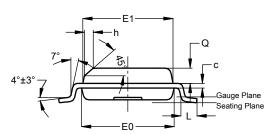
SO-14



SO-14				
Dim	Min	Max		
Α	1.47	1.73		
A1	0.10	0.25		
A2	1.45	Тур		
В	0.33	0.51		
D	8.53	8.74		
E	3.80	3.99		
е	1.27	Тур		
Ι	5.80	6.20		
L	0.38	1.27		
θ	0°	8°		
All Di	mensions	s in mm		







SO-8

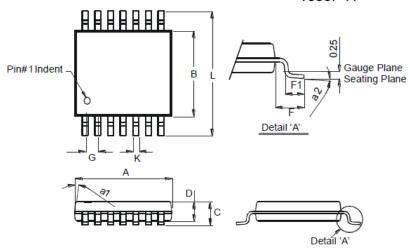
	S	D-8	
Dim	Min	Max	Тур
Α	1.40	1.50	1.45
A1	0.10	0.20	0.15
b	0.30	0.50	0.40
С	0.15	0.25	0.20
D	4.85	4.95	4.90
Е	5.90	6.10	6.00
E1	3.80	3.90	3.85
E0	3.85	3.95	3.90
е			1.27
h			0.35
L	0.62	0.82	0.72
Q	0.60	0.70	0.65
All	Dimens	ions in	mm



Package Outline Dimensions (continued)

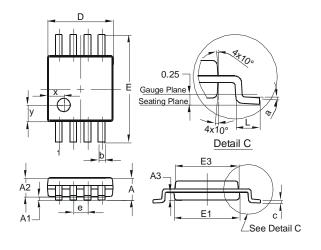
Please see http://www.diodes.com/package-outlines.html for the latest version.

TSSOP-14



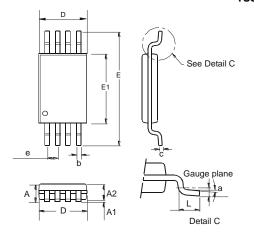
	TSSOP-14				
Dim	Min	Max			
a1	7° (4X)			
a2	0°	8°			
Α	4.9	5.10			
В	4.30	4.50			
С	-	1.2			
D	8.0	1.05			
F	1.00	Тур			
F1	0.45	0.75			
G	0.65	Тур			
K	0.19	0.30			
L 6.40 Typ					
All Dir	nensions	s in mm			

MSOP-8



MSOP-8			
Dim	Min	Max	Тур
Α	-	1.10	
A1	0.05	0.15	0.10
A2	0.75	0.95	0.86
A3	0.29	0.49	0.39
b	0.22	0.38	0.30
С	0.08	0.23	0.15
D	2.90	3.10	3.00
Е	4.70	5.10	4.90
E1	2.90	3.10	3.00
E3	2.85	3.05	2.95
е	-	1	0.65
L	0.40	0.80	0.60
а	0°	8°	4°
Х			0.750
у			0.750
All Dimensions in mm			

TSSOP-8



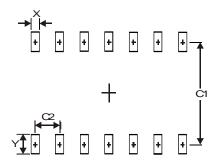
TSSOP-8			
Dim	Min	Max	Тур
а	0.09		
Α		1.20	
A1	0.05	0.15	
A2	0.825	1.025	0.925
b	0.19	0.30	
С	0.09	0.20	
ם	2.90	3.10	3.025
е			0.65
Е			6.40
E1	4.30	4.50	4.425
L	0.45	0.75	0.60
All Dimensions in mm			



Suggested Pad Layout

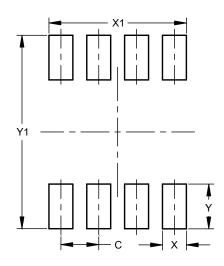
Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-14



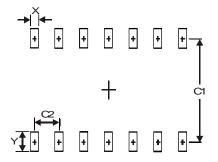
Dimensions	Value (in mm)
Х	0.60
Y	1.50
C1	5.4
C2	1.27

SO-8



Dimensions	Value (in mm)
С	1.27
Х	0.802
X1	4.612
Y	1.505
Y1	6.50

TSSOP-14



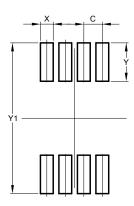
Dimensions	Value (in mm)
X	0.45
Y	1.45
C1	5.9
C2	0.65



Suggested Pad Layout (continued)

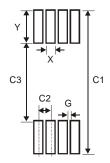
Please see http://www.diodes.com/package-outlines.html for the latest version.

MSOP-8



Dimensions	Value	
Dimensions	(in mm)	
С	0.650	
Х	0.450	
Υ	1.350	
Y1	5.300	

TSSOP-8



Dimensions	Value (in mm)
Х	0.45
Υ	1.78
C1	7.72
C2	0.65
C3	4.16
G	0.20





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